



Low-Power Error Correction for Mobile Storage

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- The ECC engine will consume a great percentage of power in the controller
- Both RAID and LDPC become crucial to high reliable flash controller, which is employed in embedded applications.
- Stronger correction capability
 - Longer ECC chunk (e.g., 2KB BCH is stronger than 1KB, and 2KB LDPC is much stronger than 1KB)
 - Higher decoder resolution and parallelism architecture will reduce the decoding latency.
 - Higher power consumption.
- Wider range corrupt data recovery
 - Larger RAID recovery range will provide wider range data recovery.
 - Consume more memory size and calculation logic.
 - Higher power consumption.
- In normal operation...
 - For RAID engine, only the encoder part is active all the time.
 - LDPC uses the hard-decoding only, but the encoder is always active in each flash write action.
- Power consumption reduction in hot region
 - RAID encoding
 - LDPC decoding



- The SSD module failure rate will be the Key for TLC adoption on SSD.
- Latest Planar NAND might be 1znm.
 - Bit column, sense-Amp, address decoder, or charge pump corrupted
 - WL lining or WL to WL short.
- First popular 3D structure on BiCs.
 - Inherit most of failure cases from 2D.
 - High aspect ratio etching and larger number of layers control will contribute more failure cases.
- No Erase/Program failure, but with reading ECC failure.
 - Need RAID engine to do the error recovery.
 - In 3D TLC, three WL lining may cause data loss over 9 pages.
- High efficiency RAID with erasure decoding.
 - Encoding with high efficiency memory access.
 - Memory access dominates the encoding power.
 - Low RAID recovery trigger rate.



[Ref]: VLSI symp. 2009, pp.136-137, VLSI symp. 2008, pp. 192-193
VLSI symp. 2010, pp. 131-132,
IEEE Trans. Electron Devices, vol.58, no.5, pp. 1006-1014, Apr.2011





- NAND Flash characteristics on Endurance and Retention.
- Retention capability on TLC degrades rapidly as P/E cycle increases.
- Reduce the power with Retention-aware algorithm:
 - Predict the sensing point in the first read.
 - Joint the soft-decoding and the Vt-tracking.
 - Minimize the number of read operation
- The error bit number is the key factor of power consumption.
 - Sensing the data which has lowest bit error rate
 - Predict error types and select the decoding strategy.





Flash Memory NAND characteristic. SLC/MLC/TLC



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TLC Error Behavior on Endurance



Memory



- X: Number of error bit
- Y: Number of ECC chunk
- Endurance 2K, 90% of the error bit number is less than 30 bits
- 2K: CSB-RBER = 2.7e-3
- 1K: CSB-RBER = 1.3e-3
 - Soft-decoding/RAID trigger rate
 - X: P/E cycle
 - After the 2.7K cycling, it needs LDPC soft-decoding.
- RAID redundant overhead ~ 0.07%.
- Double strong endurance from LDPC hard to soft decoding.
- First RAID recovery occurs on 4.5K cycles.

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1KB BCH vs. LDPC decoding power consumption TSMC40nm on TLC flash

Error bit range /1KB	ВСН	LDPC	NOTE
1~20 bit	A mW	0.9A mW	~400MB/sec
20~40 bit	B mW	1.4B mW	~400MB/sec
40~60 bit	C mW	2.6 C mW	~300MB/sec
Endurance	ВСН	LDPC	NOTE
Endurance 0~1K P/E	BCH A mW	0.9A mW	NOTE Hard-bit only
Endurance 0~1K P/E 1.~2K	BCH A mW B mW	LDPC 0.9A mW 1.4B mW	NOTE Hard-bit only Hard-bit only

If requirement is 1K cycles, Will be the BCH enough to support the TLC?









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Comparison between 1KB and 2KB **Flash** Memory SUMMIT

- Error bit under 2KB chunk is 110bit.
 - Almost 100% correctable rate for Hard-decision only. •
 - 851 MB/sec under 400MHz operation frequency. ٠
- When the error bit under 1KB chunk is 60bit.
 - Almost 100% correctable rate for Hard-decision only. •
 - 330 MB/sec under 400MHz operation frequency. •
- 1KB vs. 2KB under the same error condition





Error bit vs. Correctable ratio

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Error bit number in 2KB +224B ECC chunk/1KB+114B chunk

Ideal Solution for TLC-based SSD



- The 2KB BCH engine only has limited improvement on endurance and retention.
- LDPC ideally fits TLC and maximizes the endurance of TLC-based SSD solution.
- LDPC + RAID is the ONLY reliable solution for TLC-based SSD.



THANK YOU! Q & A

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